

Current

900V N-Channel MOSFET

900 V

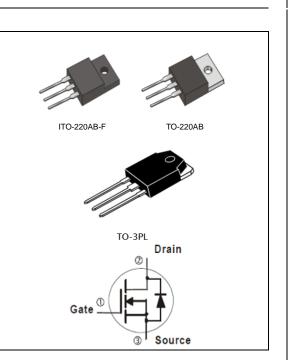
Voltage

Features

- R_{DS(ON)}, V_{GS}@10V,I_D@4.5A<1.4Ω
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance
- Lead free in compliance with EU RoHS 2011/65/EU directive.
- Green molding compound as per IEC61249 Std. (Halogen Free)

Mechanical Data

- Case : TO-220AB, ITO-220AB-F, TO-3PL Package
- Terminals : Solderable per MIL-STD-750, Method 2026
- TO-220AB Approx. Weight : 0.065 ounces, 1.859 grams
- ITO-220AB-F Approx. Weight : 0.068 ounces, 1.945 grams
- TO-3PL Approx. Weight : 0.182 ounces, 5.174grams



Maximum Ratings and Thermal Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

9 A

PARAMETER		SYMBOL	TO-220AB	ITO-220AB-F	TO-3PL	UNITS
Drain-Source Voltage		V _{DS}	900			V
Gate-Source Voltage		V _{GS}	<u>+</u> 30			V
Continuous Drain Current		I _D	9			А
Pulsed Drain Current		I _{DM}	36			А
Single Pulse Avalanche Energy (Note 1)		E _{AS}	823			mJ
Power Dissipation	T _C =25°C	P _D	205	68	240	W
	Derate above 25°C		1.64	0.54	1.92	W/°C
Operating Junction and Storage Temperature Range		T _J ,T _{STG}	-55~150			°C
Typical Thermal resistance						
- Junction to Case		$R_{ extsf{ heta}JC}$	0.61	1.84	0.52	°C/W
- Junction to Ambient		$R_{ extsf{ heta}JA}$	62.5	120	50	

• Limited only By Maximum Junction Temperature



Electrical Characteristics ($T_A=25^{\circ}C$ unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						-
Drain-Source Breakdown Voltage	BV_{DSS}	V _{GS} =0V,I _D =250uA	900	-	-	V
Gate Threshold Voltage	V _{GS(th)}	$V_{DS}=V_{GS}$, $I_{D}=250$ uA	2	-	4	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =4.5A	-	1.1	1.4	Ω
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =900V,V _{GS} =0V	-	0.03	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 30V,V _{DS} =0V	-	<u>+</u> 10	<u>+</u> 100	nA
Diode Forward Voltage	V _{SD}	I _S =9A,V _{GS} =0V	-	-	1.4	V
Dynamic (Note 4)						
Total Gate Charge	Qg		-	31	-	nC
Gate-Source Charge	Q _{gs}	$V_{DS}=720V, I_{D}=9A,$	-	8	-	
Gate-Drain Charge	Q_gd	V _{GS} =10V ^(Note 2,3)	-	12	-	
Input Capacitance	Ciss		-	1634	-	
Output Capacitance	$\frac{1}{1} V_{DS} = 25V, V_{GS} = 0V,$		-	143	-	pF
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	7.1	-	
Turn-On Delay Time	td _(on)	V _{DD} =450V, I _D =9A,	-	22	-	
Turn-On Rise Time	t _r			31	-	
Turn-Off Delay Time	td _(off)	(Note 2,3)	-	56	-	ns
Turn-Off Fall Time	t _f		-	31	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	9	А
Diode Forward Current	۱ _s					
Maximum Pulsed Drain-Source			-	-	36	A
Diode Forward Current	I _{SM}					
Reverse Recovery Time	trr	V _{GS} =0V, I _S =9A	-	657	-	ns
Reverse Recovery Charge	Qrr	dI_F/dt =100A/us ^(Note 2)	-	5.6	-	uC

NOTES :

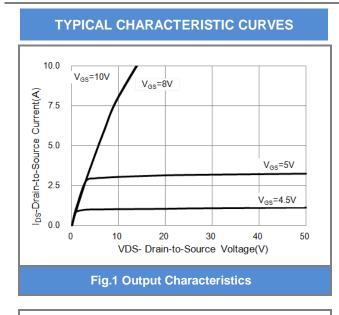
1. L=30mH, I_{AS} =7.1A, V_{DD} =50V, R_G=250hm, Starting T_J=25°C

2. Pulse width</200us, Duty cycle<2%

3. Essentially independent of operating temperature typical characteristics.

4. Guaranteed by design, not subject to production testing





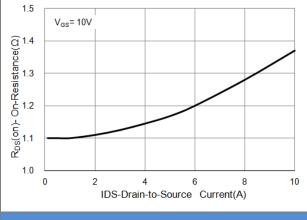
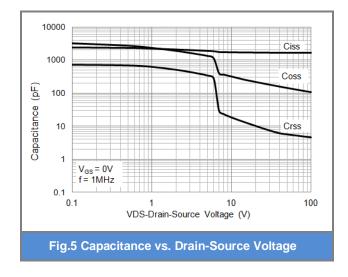


Fig.3 On-Resistance vs. Drain Current



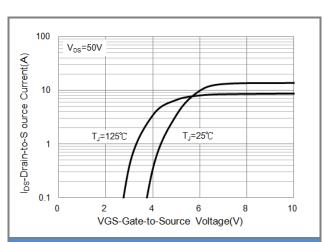


Fig.2 Transfer Characteristics

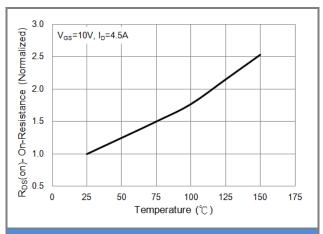
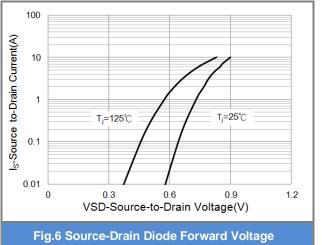
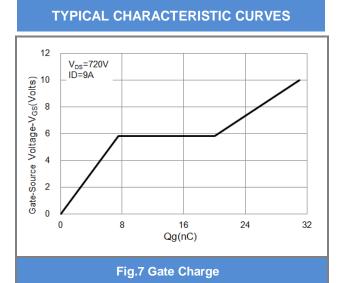


Fig.4 On-Resistance vs. Junction Temperature







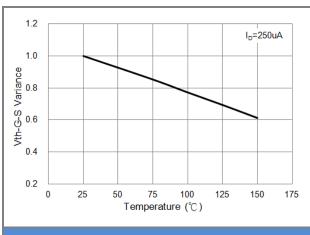
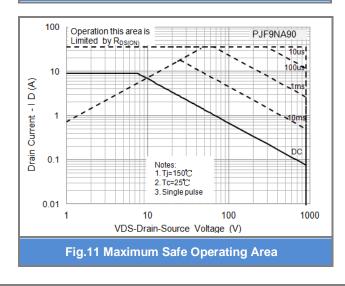


Fig.9 Threshold Voltage Variation with Temperature



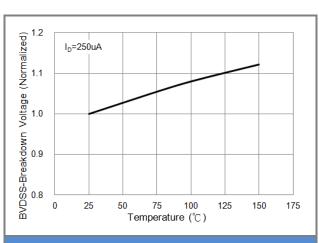


Fig.8 BV_{DSS} vs. Junction Temperature

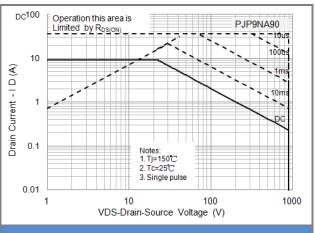
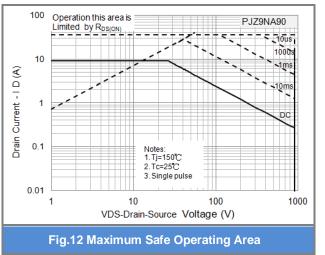
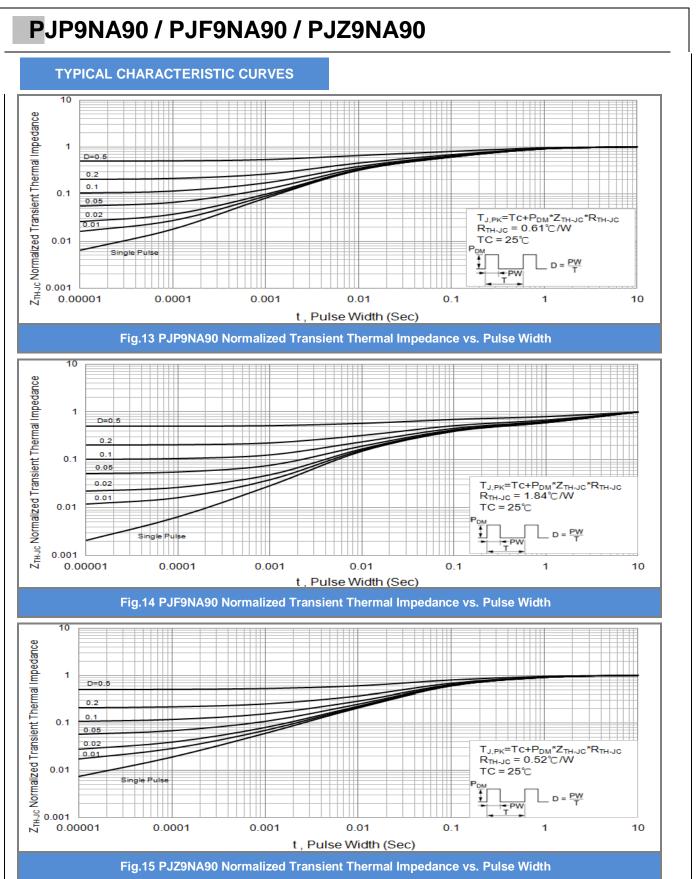


Fig.10 Maximum Safe Operating Area

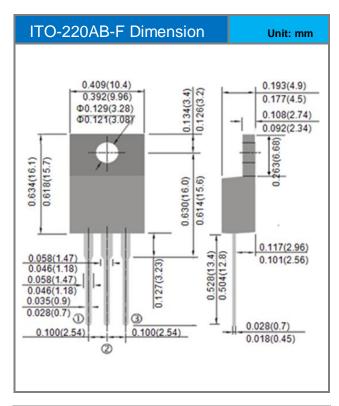


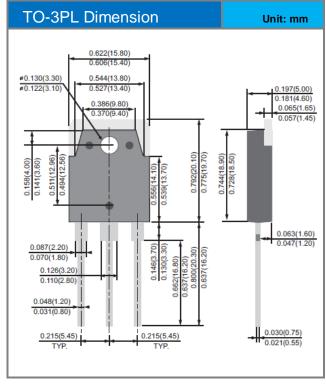


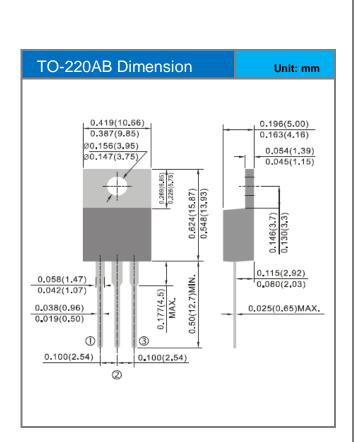




Packaging Information











PART NO PACKING CODE VERSION

Part No Packing Code	Package Type	Packing type	Marking	Version
PJP9NA90_T0_00001	TO-220AB	50pcs / Tube	P9NA90	Halogen free
PJF9NA90_T0_00001	ITO-220AB-F	50pcs / Tube	F9NA90	Halogen free
PJZ9NA90_T0_10001	TO-3PL	30pcs / Tube	Z9NA90	Rohs



PJP9NA90 / PJF9NA90 / PJZ9NA90

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